

LTC4150

Coulomb Counter/ Battery Gas Gauge

FEATURES

- Indicates Charge Quantity and Polarity
- ±50mV Sense Voltage Range
- Precision Timer Capacitor or Crystal Not Required
- 2.7V to 8.5V Operation
- High Side Sense
- 32.55Hz/V Charge Count Frequency
- 1.5µA Shutdown Current
- 10-Pin MSOP Package

APPLICATIONS

- Battery Chargers
- Palmtop Computers and PDAs
- Cellular Telephones and Wireless Modems

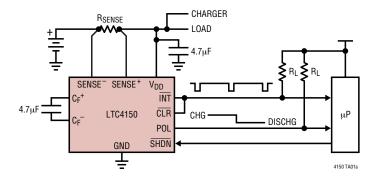
TYPICAL APPLICATION



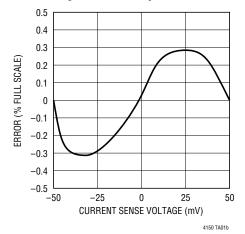
The LTC[®]4150 measures battery depletion and charging in handheld PC and portable product applications. The device monitors current through an external sense resistor between the battery's positive terminal and the battery's load or charger. A voltage-to-frequency converter transforms the current sense voltage into a series of output pulses at the interrupt pin. These pulses correspond to a fixed quantity of charge flowing into or out of the battery. The part also indicates charge polarity as the battery is depleted or charged.

The LTC4150 is intended for 1-cell or 2-cell Li-lon and 3-cell to 6-cell NiCd or NiMH applications.

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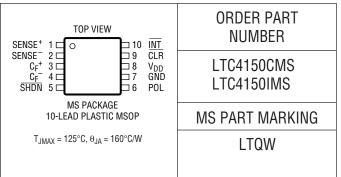


Integral Nonlinearity, % of Full Scale



(NOIG 1)
Supply Voltage (V _{DD})0.3V to 9V
Input Voltage Range
Digital Inputs ($\overline{\text{CLR}}$, $\overline{\text{SHDN}}$) – 0.3V to (V _{DD} + 0.3)
SENSE ⁻ , SENSE ⁺ , C_{F}^{-} , C_{F}^{+} 0.3V to (V_{DD} + 0.3)
Output Voltage Range
Digital Outputs (INT, POL)–0.3V to 9V
Operating Temperature Range
LTC4150CMS 0°C to 70°C
LTC4150IMS –40°C TO 85°C
Storage Temperature Range –65°C to 150°C
Lead Temperature (Soldering, 10 sec)

PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_{DD} = 2.7V and 8.5V unless otherwise noted.

$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	V _{IL}	Digital Input Low Voltage, CLR, SHDN		•			0.7	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	VIH	Digital Input High Voltage, CLR, SHDN			1.9			V
$\label{eq:lease} \begin{tabular}{ c c c c } \hline lease Qurrent, INT, POL & V_{INT} = V_{POL} = 8.5V & 0.01 & 1 & 0.01 & 1 & 0.05 & 0.01 & 0.01 & 0.05 $	V _{OL}	Digital Output Low Voltage, INT, POL	I _{OL} = 1.6mA, V _{DD} = 2.7V	•			0.5	V
$ V_{OS} \begin{tabular}{ c c c c c c } \hline V_{OD} & I & I & I & I & I & I & I & I & I & $		Digital Output Leakage Current, INT, POL	$V_{INT} = V_{POL} = 8.5V$			0.01	1	μA
$\begin{tabular}{ c c c c c c } \hline V_{DD} = 8.0V & & \pm 100 & \pm 150 & \\ \hline V_{DD} = 2.7V \ to \ 8.5V & & \pm 150 & \pm 200 & \\ \hline V_{DD} = 2.7V \ to \ 8.5V & & & \pm 150 & \pm 200 & \\ \hline V_{SENSE} & Sense \ Voltage \ Differential \ Input \ Range & SENSE + - SENSE^- & & -0.05 & 0.05 & \\ \hline R_{IDR} & Average \ Differential \ Input \ Resistance, & V_{DD} = 4.1V \ (Note \ 3) & 155 & 270 & 390 & \\ \hline Across \ SENSE + and \ SENSE^- & V_{DD} = 4.1V \ (Note \ 3) & 155 & 270 & 390 & \\ \hline V_{UUO} & Undervoltage \ Lockout \ Threshold & V_{DD} \ Rising & & 2.5 & 2.7 & \\ \hline Power \ Supply \ Current & & & & \\ \hline IDD & Supply \ Current, \ Operating & V_{DD} = 8.5V & & & 115 & 140 & \\ \hline IDD & Supply \ Current, \ Shutdown & V_{DD} = 8.5V & & & 100 & \\ \hline V_{DD} = 2.7V & & & 80 & 100 & \\ \hline V_{DD} = 2.7V & & & & 1.5 & \\ \hline AC \ Characteristics & & & & \\ \hline G_{VF} & Voltage \ Trequency \ Gain & V_{SENSE} = 50mV \ to -50mV, & & 32.0 & 32.55 & 33.1 & H \\ \hline ACyr(VDD) & Gain \ Variation \ with \ Supply & 2.7V & V_{DD} = 8.5V & & & & \\ \hline G_{VF} & Voltage \ Trequency \ Gain \ Variation \ with \ Temperature & (Note \ 2) & & & -0.03 & 0.03 & \% \\ \hline INL & Integral \ Nonlinearity & & & & & & & & \\ \hline CLR & \ CLR \ Pulse \ Width \ to \ Rest \ INT, \ INT \ and \ CLR \ Not \ Connected & & & & & & \\ \hline \end{array} $	V _{0S}	Differential Offset Voltage (Note 4)	V _{DD} = 4.0V					μι μ
$\begin{array}{ c c c c c c c } \hline & & & & & & & & & & & & & & & & & & $			V _{DD} = 8.0V	•			±100	μν μν μν
VSENSESense Voltage Differential Input RangeSENSE+ - SENSE^- \bullet -0.05 0.05 RiDRAverage Differential Input Resistance, Across SENSE+ and SENSE^- $V_{DD} = 4.1V$ (Note 3) 155 270 390 VUVL0Undervoltage Lockout Threshold $V_{DD} = 4.1V$ (Note 3) 155 270 390 Power Supply CurrentImage: Sense Voltage Differential Input Resistance, Across SENSE+ and SENSE- $V_{DD} = 4.1V$ (Note 3) 155 270 390 Power Supply CurrentImage: Sense Voltage Differential Input Resistance, Across SENSE+ and SENSE- $V_{DD} = 4.1V$ (Note 3) 155 270 390 Power Supply CurrentImage: Sense Voltage Differential Input Resistance, Across SENSE+ and SENSE- $V_{DD} = 4.1V$ (Note 3) 155 270 390 IbpSupply Current, Operating $V_{DD} = 8.5V$ $V_{DD} = 2.7V$ \bullet 115 140 $V_{DD} = 2.7V$ Ibp(SD)Supply Current, Shutdown $V_{DD} = 8.5V$ $V_{DD} = 2.7V$ \bullet 10 $V_{DD} = 2.7V$ Ibp(SD)Supply Current, Shutdown $V_{DD} = 8.5V$ $V_{DD} = 2.7V$ \bullet 10 			V _{DD} = 2.7V to 8.5V	•				μ μ
OutcolAverage Differential Input Resistance, Across SENSE* and SENSE" $V_{DD} = 4.1V$ (Note 3)155270390 V_{UVLO} Undervoltage Lockout Threshold V_{DD} Rising•2.52.7Power Supply Current I_{DD} Supply Current, Operating $V_{DD} = 8.5V$ $V_{DD} = 2.7V$ •115140 80 I_{DD} Supply Current, Shutdown $V_{DD} = 8.5V$ 	V _{SENSE(CM)}	Sense Voltage Common Mode Input Range		•	$V_{DD} - 0.06$		V _{DD} + 0.06	V
Across SENSE+ and SENSE-Doe of the set INT, INT and CLR Not ConnectedVoluteImage: Sense for the sent Integral NonlinearityAcross SENSE+ and SENSE-Image: Sense for the sent INT, Image: Sense for the sent Integral NonlinearityVoluteVoluteImage: Sense for the sent Integral NonlinearityVulueUndervoltage Lockout ThresholdVoluteVoluteVoluteImage: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityVoluteVoluteVoluteVoluteImage: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityVoluteIntegral NonlinearityFigure 2Image: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityIntegral NonlinearityIntegral NonlinearityImage: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityIntegral NonlinearityImage: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityImage: Sense for the sent Integral NonlinearityIntegral NonlinearityImage: Sense for the sent Integral NonlinearityImage: Sense	V _{SENSE}	Sense Voltage Differential Input Range	SENSE ⁺ – SENSE ⁻	•	-0.05		0.05	V
Other Supply CurrentPower Supply CurrentIDDSupply Current, Operating $V_{DD} = 8.5V$ $V_{DD} = 2.7V$ •115140 80 IDD(SD)Supply Current, Shutdown $V_{DD} = 8.5V$ $V_{DD} = 2.7V$ •10 $V_{DD} = 2.7V$ AC Characteristics G_{VF} Voltage to Frequency Gain $V_{SENSE} = 50mV$ to $-50mV$, $2.7V \le V_{DD} \le 8.5V$ 32.032.533.1H 31.8 $AG_{VF}(V_{DD})$ Gain Variation with Supply $2.7V \le V_{DD} \le 8.5V$ •00.50 $AG_{VF}(TEMP)$ Gain Variation with Temperature(Note 2)• -0.4 0.4-0.50.5 INL Integral NonlinearityFigure 22020Integral Not ConnectedFigure 220	R _{IDR}		V _{DD} = 4.1V (Note 3)		155	270	390	kΩ
IDDSupply Current, Operating $V_{DD} = 8.5V$ $V_{DD} = 2.7V$ 115140 80IDD(SD)Supply Current, Shutdown $V_{DD} = 8.5V$ $V_{DD} = 8.5V$ $V_{DD} = 2.7V$ 10 1.5AC Characteristics G_{VF} Voltage to Frequency Gain $V_{SENSE} = 50mV \text{ to } -50mV,$ $2.7V \le V_{DD} \le 8.5V$ 32.0 31.832.55 33.1 33.3 $\Delta G_{VF}(V_{DD})$ Gain Variation with Supply $2.7V \le V_{DD} \le 8.5V$ 00.5 $\Delta G_{VF}(TEMP)$ Gain Variation with Temperature(Note 2) -0.4 -0.5 0.4 -0.5 NL Integral Nonlinearity -0.5 0.5 -0.5 0.5 t_{CLR} \overline{CLR} Pulse Width to Reset INT, INT and \overline{CLR} Not ConnectedFigure 220	V _{UVLO}	Undervoltage Lockout Threshold	V _{DD} Rising			2.5	2.7	V
Image: constraint of the section o	Power Supply	v Current					I	
AC Characteristics $V_{DD} = 2.7V$ •1.5AC Characteristics $V_{SENSE} = 50mV \text{ to } -50mV,$ $2.7V \le V_{DD} \le 8.5V$ 32.0 31.8 32.55 33.3 33.1 33.3 $\Delta G_{VF}(V_{DD})$ Gain Variation with Supply $2.7V \le V_{DD} \le 8.5V$ 00.5 $\Delta G_{VF}(TEMP)$ Gain Variation with Temperature(Note 2)• -0.03 0.03%INLIntegral Nonlinearity-0.4 1.5 0.4 -0.5 0.51.5tcLR \overline{CLR} Pulse Width to Reset \overline{INT} , \overline{INT} and \overline{CLR} Not ConnectedFigure 22020	I _{DD}	Supply Current, Operating						4μ μ
G_{VF} Voltage to Frequency Gain $V_{SENSE} = 50mV$ to $-50mV$, $2.7V \le V_{DD} \le 8.5V$ 32.0 31.8 32.55 33.3 33.1 	I _{DD(SD)}	Supply Current, Shutdown						μμ μμ
$\Delta G_{VF}(V_{DD})$ Gain Variation with Supply $2.7V \le V_{DD} \le 8.5V$ \odot 31.8 33.3 H $\Delta G_{VF}(V_{DD})$ Gain Variation with Supply $2.7V \le V_{DD} \le 8.5V$ 0 0.5 O $\Delta G_{VF}(TEMP)$ Gain Variation with Temperature(Note 2) \bullet -0.03 0.03 $\%$ INLIntegral Nonlinearity -0.4 0.4 -0.5 0.5 0.5 t_{CLR} \overline{CLR} Pulse Width to Reset INT, INT and CLR Not ConnectedFigure 2 20 20 1000	AC Character	istics					I	
$\Delta G_{VF}(TEMP)$ Gain Variation with Temperature(Note 2) -0.03 0.03 %INLIntegral Nonlinearity -0.4 0.4 t_{CLR} \overline{CLR} Pulse Width to Reset INT, INT and \overline{CLR} Not ConnectedFigure 220	G _{VF}	Voltage to Frequency Gain		•		32.55		Hz/V Hz/V
INLIntegral Nonlinearity -0.4 0.4 INLIntegral Nonlinearity -0.5 0.5 t_{CLR} \overline{CLR} Pulse Width to Reset INT, INT and \overline{CLR} Not ConnectedFigure 220	$\Delta G_{VF}(V_{DD})$	Gain Variation with Supply	$2.7V \le V_{DD} \le 8.5V$		0		0.5	%/\
Image: transmission of the transmission of transm	$\Delta G_{VF}(TEMP)$	Gain Variation with Temperature	(Note 2)		-0.03		0.03	%/ °C
INT and CLR Not Connected	INL	Integral Nonlinearity		•				%
t_{INT} INT Low Time, INT Connected to \overline{CLR} Figure 3, $C_1 = 15pF$ 1	t _{CLR}	/	Figure 2		20			μ
	t _{INT}	INT Low Time, INT Connected to CLR	Figure 3, C _L = 15pF		1			μs



ELECTRICAL CHARACTERISTICS

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

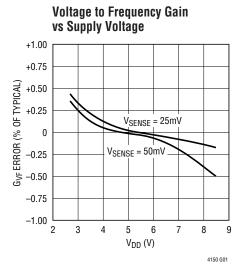
Note 2: Guaranteed by design and not tested in production.

Note 3: Measured at least 20ms after power on. **Note 4:** Tested in feedback loop to SENSE⁺ and SENSE⁻.

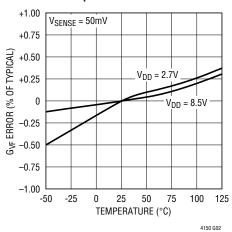
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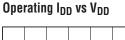
TYPICAL PERFORMANCE CHARACTERISTICS (Specifications are at $T_A = 25$ °C, unless otherwise noted.)

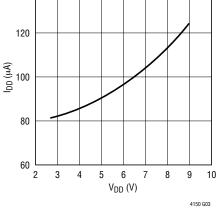




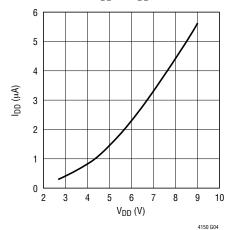
Voltage to Frequency Gain vs Temperature



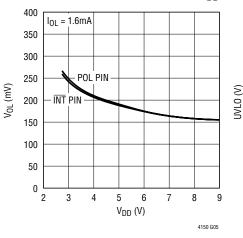




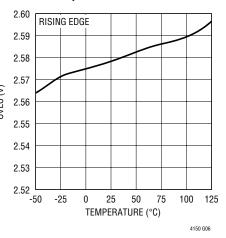
Shutdown I_{DD} vs V_{DD}



Digital Output Low Voltage vs V_{DD}



Undervoltage Lockout Threshold vs Temperature



TECHNOLOGY

PIN FUNCTIONS

SENSE⁺ (Pin1): Positive Sense Input. This is the noninverting current sense input. Connect SENSE⁺ to the load and charger side of the sense resistor. Full-scale current sense input is 50mV. SENSE⁺ must be within 60mV of V_{DD} for proper operation.

SENSE⁻ (Pin 2): Negative Sense Input. This is the inverting current sense input. Connect SENSE⁻ to the positive battery terminal side of the sense resistor. Full-scale current sense input is 50 mV. SENSE⁻ must be within 60 mV of V_{DD} for proper operation.

 C_F^+ (Pin 3): Filter Capacitor Positive Input. A capacitor connected between C_F^+ and C_F^- filters and averages noise and fast battery current variations. A 4.7 μ F value is recommended. If filtering is not desired, leave C_F^+ and C_F^- unconnected.

 C_F^- (Pin 4): Filter Capacitor Negative Input. A capacitor connected between C_F^+ and C_F^- filters and averages noise and fast battery current variations. A 4.7 μ F value is recommended. If filtering is not desired, leave C_F^+ and C_F^- unconnected.

SHDN (Pin 5): Shutdown Digital Input. When asserted low, SHDN forces the LTC4150 into its low current consumption power-down mode and resets the part. In applications with logic supply $V_{CC} > V_{DD}$, a resistive divider must be used between SHDN and the logic which drives it. See the Applications Information section.

POL (Pin 6): Battery Current Polarity Open-Drain Output. POL indicates the most recent battery current polarity when INT is high. A low state indicates the current is flowing out of the battery while high impedance means the current is going into the battery. POL latches its state when INT is asserted low. POL is an open-drain output and can be pulled up to any logic supply up to 9V. In shutdown, POL is high impedance.

GND (Pin 7): Ground. Connect directly to the negative battery terminal.

 V_{DD} (Pin 8): Positive Power Supply. Connect to the load and charger side of the sense resistor. SENSE⁺ also connects to V_{DD}. V_{DD} operating range is 2.7V to 8.5V. Bypass V_{DD} with 4.7µF capacitor.

CLR (Pin 9): Clear Interrupt Digital Input. When asserted low for more than 20μ s, CLR resets INT high. Charge counting is *unaffected*. INT may be directly connected to CLR. In this case the LTC4150 will capture each assertion of INT and wait at least 1μ s before resetting it. This ensures that INT pulses low for at least 1μ s but gives automatic INT reset. In applications with a logic supply V_{CC} > V_{DD}, a resistive divider must be used between INT and CLR. See the Applications Information section.

INT (Pin 10): Charge Count Interrupt Open-Drain Output. INT latches low every $1/(V_{SENSE} \bullet G_{VF})$ seconds and is reset by a low pulse at CLR. INT is an open-drain output and can be pulled up to any logic supply of up to 9V. In shutdown INT is high impedance.



4150fa

BLOCK DIAGRAM

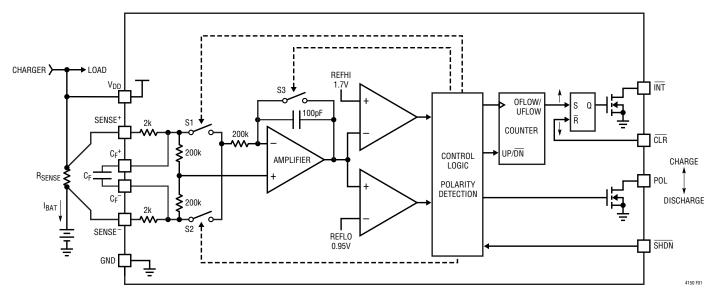


Figure 1. Block Diagram

TIMING DIAGRAMS

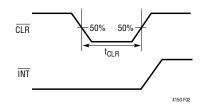


Figure 2. CLR Pulse Width to Reset INT, CLR and INT Not Connected

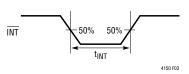


Figure 3. $\overline{\text{INT}}$ Minimum Pulse Width, $\overline{\text{CLR}}$ and $\overline{\text{INT}}$ Connected



OPERATION

Charge is the time integral of current. The LTC4150 measures battery current by monitoring the voltage developed across a sense resistor and then integrates this information in several stages to infer charge. The Block Diagram shows the stages described below. As each unit of charge passes into or out of the battery, the LTC4150 INT pin interrupts an external microcontroller and the POL pin reports the polarity of the charge unit. The external microcontroller then resets INT with the CLR input in preparation for the next interrupt issued by the LTC4150. The value of each charge unit is determined by the sense resistor value and the sense voltage to interupt frequency gain G_{VF} of the LTC4150.

Power-On and Start-Up Initialization

When power is first applied to the LTC4150, all internal circuitry is reset. After an initialization interval, the LTC4150 begins counting charge. This interval depends on V_{DD} and the voltage across the sense resistor but will be at least 5ms. It may take an additional 80ms for the LTC4150 to accurately track the sense voltage. An internal undervoltage lockout circuit monitors V_{DD} and resets all circuitry when V_{DD} falls below 2.5V.

Asserting SHDN low also resets the LTC4150's internal circuitry and reduces the supply current to 1.5μ A. In this condition, POL and INT outputs are high impedance. The LTC4150 resumes counting after another initialization interval. Shutdown minimizes battery drain when both the charger and load are off.

CHARGE COUNTING

First, the current measurement is filtered by capacitor C_F connected across pins C_F^+ and C_F^- . This averages fast changes in current arising from ripple, noise and spikes in the load or charging current.

Second, the filter's output is applied to an integrator with the amplifier and 100pF capacitor at its core. When the integrator output ramps to REFHI or REFLO levels, switches S1 and S2 reverse the ramp direction. By observing the condition of S1 and S2 and the ramp direction, polarity is determined. The integrating interval is trimmed to $600\mu s$ at 50mV full-scale sense voltage.

Third, a counter is incremented or decremented every time the integrator changes ramp direction. The counter effectively increases integration time by a factor of 1024, greatly reducing microcontroller overhead required to service interrupts from the LTC4150.

At each counter under or overflow, the INT output latches low, flagging a microcontroller. Simultaneously, the POL output is latched to indicate the polarity of the observed charge. With this information, the microcontroller can total the charge over long periods of time, developing an accurate estimate of the battery's condition. Once the interrupt is recognized, the microcontroller resets INT with a low going pulse on CLR and awaits the next interrupt. Alternatively, INT can drive CLR.



SENSE VOLTAGE INPUT AND FILTERS

Since the overall integration time is set by internally trimming the LTC4150, no external timing capacitor or trimming is necessary. The only external component that affects the transfer function of interrupts per coulomb of charge is the sense resistor, R_{SENSE} . The common mode range for the SENSE⁺ and SENSE⁻ pins is $V_{DD} \pm 60$ mV, with a maximum differential voltage range of ± 50 mV. SENSE⁺ is normally tied to V_{DD} , so there is no common mode issue when SENSE⁻ operates within the 50mV differential limit relative to SENSE⁺.

Choose R_{SENSE} to provide 50mV drop at maximum charge or discharge current, whichever is greater. Calculate R_{SENSE} from:

$$R_{SENSE} = \frac{50 \text{mV}}{I_{MAX}} \tag{1}$$

The sense input range is small (\pm 50mV) to minimize the loss across R_{SENSE}. To preserve accuracy, use Kelvin connections at R_{SENSE}.

The external filter capacitor C_F operates against a total onchip resistance of 4k to form a lowpass filter that averages battery current and improves accuracy in the presence of noise, spikes and ripple. 4.7 μ F is recommended for general applications but can be extended to higher values as long as the capacitor's leakage is low. A 10nA leakage is roughly equivalent to the input offset error of the integrator. Ceramic capacitors are suitable for this use.

Switching regulators are a particular concern because they generate high levels of current ripple which may flow through the battery. The V_{DD} and SENSE⁺ connection to the charger and load should be bypassed by at least $4.7\mu F$ at the LTC4150 if a switching regulator is present.

The LTC4150 maintains high accuracy even when Burst Mode[®] switching regulators are used. Burst pulse "on" levels must be within the specified differential input voltage range of 50mV as measured at C_F^+ and C_F^- . To retain accurate charge information, the LTC4150 must remain enabled during Burst Mode operation. If the LTC4150 shuts down or V_{DD} drops below 2.5V, the part resets and charge information is lost.

Coulomb Counting

The LTC4150's transfer function is quantified as a voltage to frequency gain G_{VF} , where output frequency is the number of interrupts per second and input voltage is the differential drive V_{SENSE} across SENSE⁺ and SENSE⁻. The number of interrupts per second will be:

$$f = G_{VF} \bullet |V_{SENSE}|$$
(2)

where

$$V_{SENSE} = I_{BATTERY} \bullet R_{SENSE}$$
(3)

Therefore,

$$f = G_{VF} \bullet | I_{BATTERY} \bullet R_{SENSE} |$$
(4)

Since $I \bullet t = Q$, coulombs of battery charge per \overline{INT} pulse can be derived from Equation 4:

One
$$\overline{INT} = \frac{1}{G_{VF} \bullet R_{SENSE}}$$
 Coulombs (5)

Battery capacity is most often expressed in ampere-hours.

Combining Equations 5 and 6:

One
$$\overline{INT} = \frac{1}{3600 \bullet G_{VF} \bullet R_{SENSE}}$$
 [Ah] (7)

or

$$1Ah = 3600 \bullet G_{VF} \bullet R_{SENSE} \text{ Interrupts}$$
(8)

The charge measurement may be further scaled within the microcontroller. However, the number of interrupts, coulombs or Ah all represent battery charge.

The LTC4150's transfer function is set only by the value of the sense resistor and the gain G_{VF} . Once R_{SENSE} is selected using Equation 1, the charge per interrupt can be determined from Equation 5 or 7.

Note that R_{SENSE} is not chosen to set the relationship between ampere-hours of battery charge and number of interrupts issued by the LTC4150. Rather, R_{SENSE} is chosen to keep the maximum sense voltage equal to or less than the LTC4150's 50mV full-scale sense input.

Burst Mode is registered trademark of Linear Technology Corporation.



$\overline{\text{INT}}, \text{ POL} \text{ and } \overline{\text{CLR}}$

INT asserts low each time the LTC4150 measures a unit of charge. At the same time, POL is latched to indicate the polarity of the charge unit. The integrator and counter continue running, so the microcontroller must service and clear the interrupt before another unit of charge accumulates. Otherwise, one measurement will be lost. The time available between interrupts is the reciprocal of Equation 2:

$$Fine \text{ per } \overline{INT} \text{ Assertion} = \frac{1}{G_{VF} \bullet |V_{SENSE}|}$$
(9)

At 50mV full scale, the minimum time available is 596ms. To be conservative and accommodate for small, unexpected excursions above the 50mV sense voltage limit, the microcontroller should process the interrupt and polarity information and clear INT within 500ms.

Toggling $\overline{\text{CLR}}$ low for at least $20\mu\text{s}$ resets $\overline{\text{INT}}$ high and unlatches POL. Since the LTC4150's integrator and counter operate independently of the $\overline{\text{INT}}$ and POL latches, no charge information is lost during the latched period or while CLR is low. Charge/discharge information continues to accumulate during those intervals and accuracy is unaffected.

Once cleared, INT idles in a high state and POL indicates real-time polarity of the battery current. POL high indicates charge flowing into the battery and low indicates charge flowing out. Indication of a polarity change requires at least:

$$t_{\text{POL}} = \frac{2}{G_{\text{VF}} \bullet 1024 \bullet |V_{\text{SENSE}}|}$$
(10)

where $V_{\mbox{SENSE}}$ is the smallest sense voltage magnitude before and after the polarity change.

Open-drain outputs POL and \overline{INT} can sink I_{OL} = 1.6mA at V_{OL} = 0.5V. The minimum pull-up resistance for these pins should be:

$$R_L > (V_{CC} - 0.5) / 1.6 mA$$
 (11)

where V_{CC} is the logic supply voltage. Because speed isn't an issue, pull-up resistors of 10k or higher are adequate.

Interfacing to $\overline{\text{INT}}, \text{ POL}, \overline{\text{CLR}} \text{ and } \overline{\text{SHDN}}$

The LTC4150 operates directly from the battery, while in most cases the microcontroller supply comes from some separate, regulated source. This poses no problem for INT and POL because they are open-drain outputs and can be pulled up to any voltage 9V or less, regardless of the voltage applied to the LTC4150's V_{DD} .

 $\overline{\text{CLR}}$ and $\overline{\text{SHDN}}$ inputs require special attention. To drive them, the microcontroller or external logic must generate a minimum logic high level of 1.9V. The maximum input level for these pins is V_{DD} + 0.3V. If the microcontroller's supply is more than this, resistive dividers must be used on $\overline{\text{CLR}}$ and $\overline{\text{SHDN}}$. The schematic in Figure 6 shows an application with INT driving $\overline{\text{CLR}}$ and microcontroller V_{CC} > V_{DD}. The resistive dividers on $\overline{\text{CLR}}$ and $\overline{\text{SHDN}}$ keep the voltages at these pins within the LTC4150's V_{DD} range. Choose R2 and R1 so that:

$$(R1 + R2) \ge 50R_L \tag{12}$$

$$1.9V \le \frac{R1}{R1 + R2} V_{CC} \le V_{DD} \text{ (Minimum)}$$
(13)

Equation 13 also applies to the selection of R3 and R4. The minimum V_{DD} is the lowest supply to the LTC4150 when the battery powering it is at its lowest discharged voltage.

When the battery is removed in any application, the $\overline{\text{CLR}}$ and $\overline{\text{SHDN}}$ inputs are unpredictable. INT and POL outputs may be erratic and should be ignored until after the battery is replaced.

If desired, the simple logic of Figure 4 may be used to derive separate charge and discharge pulse trains from $\overline{\text{INT}}$ and POL.

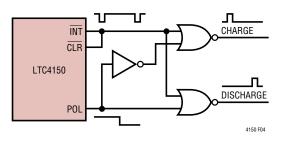


Figure 4. Unravelling Polarity— Separate Charge and Discharge Outputs



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AUTOMATIC CHARGE COUNT INTERRUPT AND CLEAR

In applications where a $\overline{\text{CLR}}$ pulse is unavailable, it's easy to make the LTC4150 run autonomously, as shown in Figures 5 and 6. If the microcontroller V_{CC} is less than or equal to the battery V_{DD} , $\overline{\text{INT}}$ may be directly connected to $\overline{\text{CLR}}$, as in Figure 5. The only requirement is that the microcontroller should be able to provide a high logic level of 1.9V to SHDN. If the microcontroller V_{CC} is greater than

the battery V_{DD} , use Figure 6. The resistor dividers on \overline{CLR} and \overline{SHDN} keep the voltages at these pins within the LTC4150's V_{DD} range. Choose an R_L value using Equation 11 and R1-R4 values using Equation 13. In either application, the LTC4150 will capture the first assertion of INT and wait at least 1µs before resetting it. This insures that INT pulses low for at least 1µs but gives automatic INT reset.

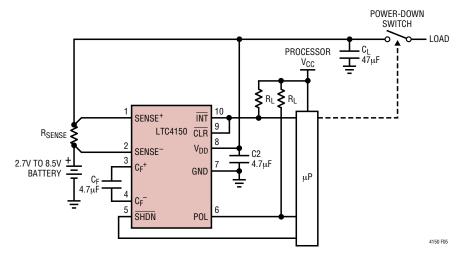


Figure 5. Application with $\overline{\text{INT}}$ Direct Drive of $\overline{\text{CLR}}$ and Separate Microprocessor Supply $V_{\text{CC}} \leq V_{DD}$

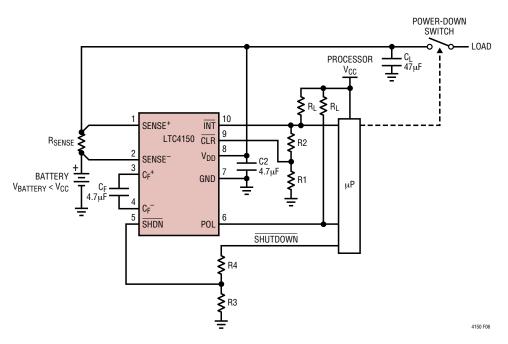


Figure 6. Application with INT Driving $\overline{\text{CLR}}$ and Separate Microprocessor Supply $V_{CC} > V_{DD}$



PC BOARD LAYOUT SUGGESTIONS

Keep all traces as short as possible to minimize noise and inaccuracy. The supply bypass capacitor C2 should be placed close to the LTC4150. The 4.7μ F filter capacitor C_F should be placed close the C_F⁺ and C_F⁻ pins and should be a low leakage, unpolarized type. Use a 4-wire Kelvin sense connection for the sense resistor, locating it close to the LTC4150 with short sense traces to the SENSE⁺ and SENSE⁻ pins and longer force lines to the battery pack and powered load, see Figure 7.

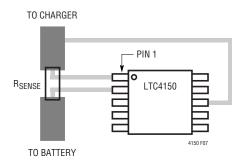


Figure 7. Kelvin Connection on SENSE Resistor

TYPICAL APPLICATIONS

Figure 8 shows a typical application designed for a single cell lithium-ion battery and 500mA maximum load current. Use Equation 1 to calculate $R_{SENSE} = 0.05V / 0.5A = 0.1\Omega$.

With $R_{SENSE} = 0.1\Omega$, Equation 7 shows that each interrupt corresponds to 0.085mAh. Equation 14, derived from Equation 2, gives the number of INT assertions for average battery current, I_{BATT} , over a time, t, in seconds:

$$\overline{INT} \text{ Assertions} = G_{VF} \bullet I_{BATT} \bullet R_{SENSE} \bullet t$$
(14)

Loading the battery so that 51.5mA is drawn from it over 600 seconds results in 100 INT assertions. For an 800mAh battery, this is $(51.5mA \cdot 1/6h) / 800mAh = 11\%$ of the battery's capacity.

With a microcontroller supply = 5V, Equation 11 gives $R_L > 2.875k$. The nearest standard value is 3k.

From Equation 12, $R_L = 3k$ gives R1 + R2 equal to 150.5k. A single cell lithium-ion battery can discharge as low as 2.7V.

From Equation 13, select R1 = 75k; the nearest standard value for R2 is 76.8k.

Also from Equation 13, we choose R3 = 75k and R4 = 76.8k.

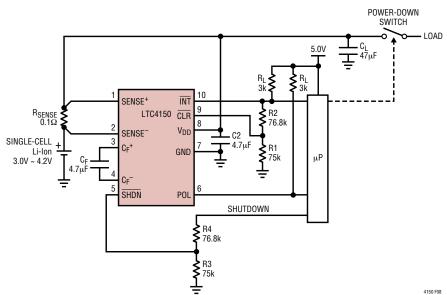
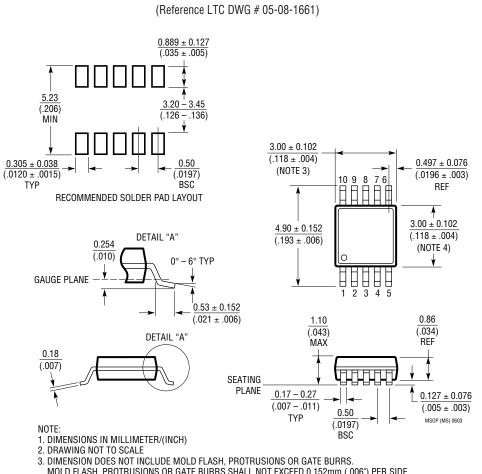


Figure 8. Typical Application, Single Cell Lithium-Ion Battery



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PACKAGE DESCRIPTION



MS Package 10-Lead Plastic MSOP

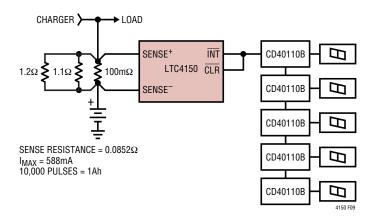
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE

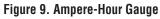
4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.

INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE 5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX



TYPICAL APPLICATIONS





RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS			
LTC1732	Lithium-Ion Linear Battery Charger Controller	Simple Charger uses External FET, Features Preset Voltages, C/10 Charger Detection and Programmable Timer, Input Power Good Indication			
LTC1733	Monolithic Lithium-Ion Linear Battery Charger	Standalone Charger with Programmable Timer, Up to 1.5A Charge Current			
LTC1734	Lithium-Ion Linear Battery Charger in ThinSOT™	Simple ThinSOT Charger, No Blocking Diode, No Sense Resistor Needed			
LTC1734L	Lithium-Ion Linear Battery Charger in ThinSOT	Low Current Version of LTC1734			
LTC1998	Lithium-Ion Low Battery Detector	1% Accurate 2.5µA Quiescent Current, SOT-23			
LTC4006	Small, High Efficiency, Fixed Voltage, Lithium-Ion Battery Charger	Constant-Current/Constant Voltage Switching Regulator with Termination Timer, AC Adapter Current Limit and Thermistor Sensor in a Small 16-Pin Package			
LTC4050	Lithium-Ion Linear Battery Charger Controller	Simple Charger uses External FET, Features Preset Voltages, C/10 Charger Detection and Programmable Timer, Input Power Good Indication, Thermistor Interface			
LTC4052	Monolithic Lithium-Ion Battery Pulse Charger	No Blocking Diode or External Power FET Required, Safety Current Limit			
LTC4053	USB Compatible Monolithic Lithium-Ion Battery Charger	Standalone Charger with Programmable Timer, Up to 1.25A Charge Current			
LTC4054	800mA Standalone Linear Lithium-Ion Battery Charger with Thermal Regulation in ThinSOT	No External MOSFET, Sense Resistor or Blocking Diode Required, Charge Current Monitor for Gas Gauging, C/10 Charge Termination			
LTC4410	USB Power Manager	For Simultaneous Operation of USB Peripheral and Battery Charging from USB Port, Keeps Current Drawn from USB Port Constant, Keeps Battery Fresh, Use with the LTC4053, LTC1733, LTC4054			
LTC4412	PowerPath™ Controller in ThinSOT	More Efficient Diode OR'ing, Automatic Switching Between DC Sources, Simplified Load Sharing, $3V \le V_{IN} \le 28V$			

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